Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|------------------------------------------------------|
| Glass and metal |
| Overall Length: |
| 2.380 inches |
| Overall Height: |
| 1.000 inches |
| Overall Width: |
| 1.000 inches |
| Mounting Method: |
| Compression |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 1200.0 reverse voltage, peak |
| Current Rating Per Characteristic: |
| 15.00 amperes forward current, average absolute |
| Maximum Operating Tempurature Per Measurement Point: |
| 125.0 degrees celsius ambient air |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |

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